



P-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	RDS(ON) Max	I _D Tc = +25°C
-40V	15mΩ @ V _{GS} = -10V	-61A
	23mΩ @ V _{GS} = -4.5V	-49A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Reverse Polarity Protection
- BLDC Motor Control
- Power Management Functions

Features and Benefits

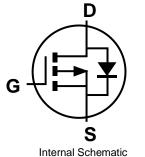
- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low On-Resistance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMP4013SPSQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

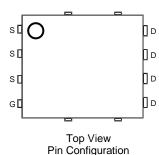
https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: PowerDI[®]5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish 100% Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (23)
- Weight: 0.097 grams (Approximate)







Ordering Information (Note 4)

Part Number	Case	Packaging
DMP4013SPSQ-13	PowerDI5060-8	2,500 / Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



);; = Manufacturer's Marking P4013SS = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 20 = 2020) WW = Week (01 to 53)

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Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	VDSS	-40	V		
Gate-Source Voltage	Vgss	±20	V		
Continuous Drain Current V _{GS} = -10V (Note 7)	Steady State	T _C = +25°C T _C = +70°C	lο	-61 -49	А
Continuous Drain Current V _{GS} = -10V (Note 6)	Steady State	$T_A = +25$ °C $T_A = +70$ °C	lο	-11 -9	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	-244	Α		
Maximum Body Diode Continuous Current (Note 7)	Is	-61	A		
Pulsed Source Current (10µs Pulse, Duty Cycle = 1%)	Ism	-244	Α		
Avalanche Current (Note 8) L = 1mH	I _{AS}	-16	A		
Avalanche Energy (Note 8) L = 1mH	Eas	176	mJ		

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	T _A = +25°C	PD	1.6	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	96	°C/W
Total Power Dissipation (Note 6)	T _A = +25°C	PD	3.4	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	44	°C/W
Thermal Resistance, Junction to Case (Note 7)	Reлc	1.5	°C/W	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

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Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BVDSS	-40	_	_	V	$V_{GS} = 0V, I_{D} = -250\mu A$	
Zero Gate Voltage Drain Current	IDSS	_	_	-1	μΑ	$V_{DS} = -40V$, $V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	Vgs(TH)	-1	_	-3	V	$V_{DS} = V_{GS}$, $I_D = -250\mu A$	
Static Drain-Source On-Resistance	Descous		9.6	15		$V_{GS} = -10V, I_{D} = -10A$	
Static Dialii-Source Oil-Resistance	RDS(ON)	_	13.4	23	mΩ	$V_{GS} = -4.5V, I_{D} = -8A$	
Diode Forward Voltage	V_{SD}	_	-0.7	-1.2	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	Ciss	_	4004	_		.,	
Output Capacitance	Coss		309		pF	$V_{DS} = -20V$, $V_{GS} = 0V$ f = 1MHz	
Reverse Transfer Capacitance	Crss	_	229	_			
Gate Resistance	R_g		3.5		Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = -4.5V)	Qg	_	31	_			
Total Gate Charge (V _{GS} = -10V)	Qg	_	67	_	nC	V _{DS} = -20V, I _D = -10A	
Gate-Source Charge	Qgs	_	13.2	_	IIC	DS = -20V, ID = -10A	
Gate-Drain Charge	Qgd	_	11	_			
Turn-On Delay Time	t _{D(ON)}	_	9.9	_			
Turn-On Rise Time	t _R	_	32	_		$V_{GS} = -10V, V_{DD} = -20V,$	
Turn-Off Delay Time	t _{D(OFF)}	_	46	_	ns	$R_G = 3\Omega$, $I_D = -10A$	
Turn-Off Fall Time	t _F	_	53	_			
Reverse Recovery Time	trr	_	19.5	_	ns	I _F = -10A, di/dt = -100A/μs	
Reverse Recovery Charge	Q _{RR}	_	11.6	_	nC	I _F = -10A, di/dt = -100A/µs	

Notes: 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
 7. Thermal resistance from junction to soldering point (on the exposed drain pad).
- 8. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep T_J = +25°C.
- 9. Short duration pulse test used to minimize self-heating effect.
- 10. Guaranteed by design. Not subject to product testing.



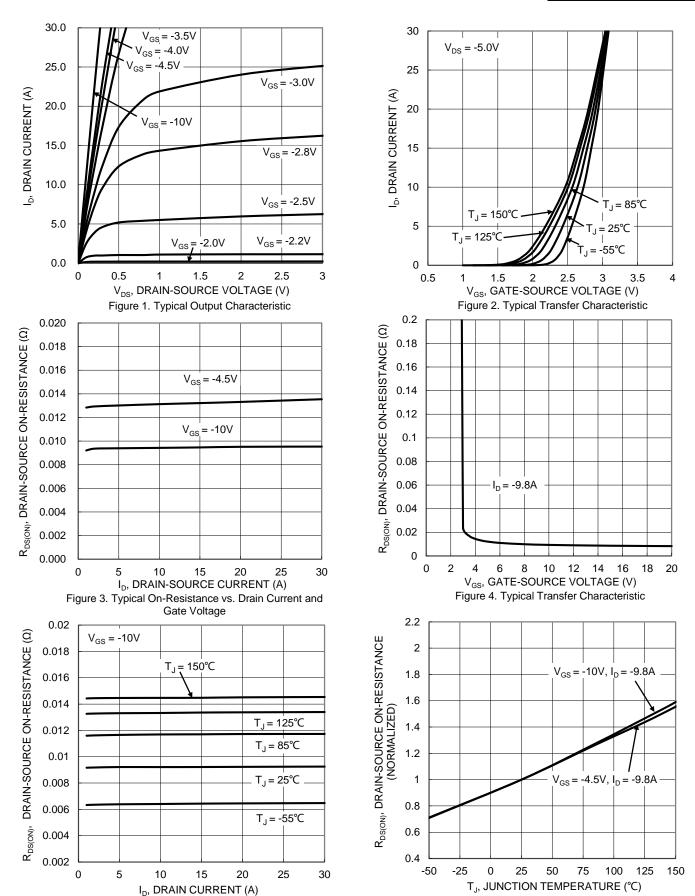


Figure 5. Typical On-Resistance vs. Drain Current and Temperature

Figure 6. On-Resistance Variation with Temperature



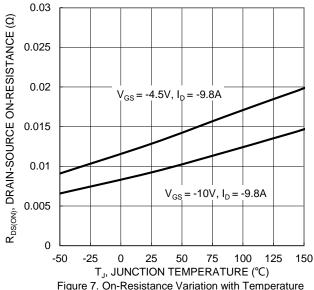
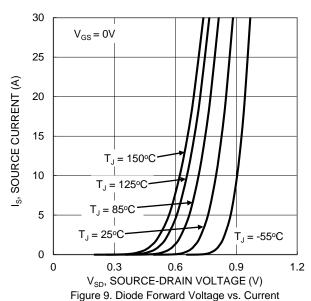


Figure 7. On-Resistance Variation with Temperature



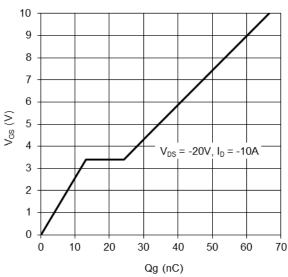


Figure 11. Gate Charge

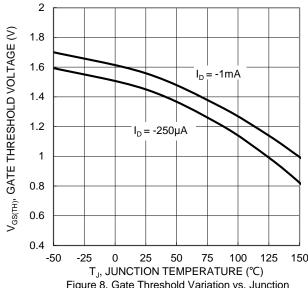


Figure 8. Gate Threshold Variation vs. Junction Temperature

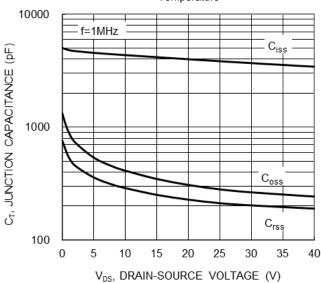


Figure 10. Typical Junction Capacitance

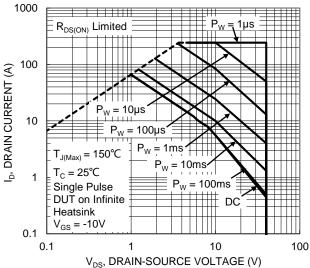


Figure 12. SOA, Safe Operation Area



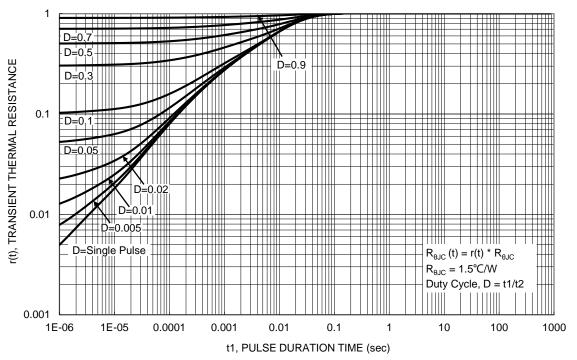


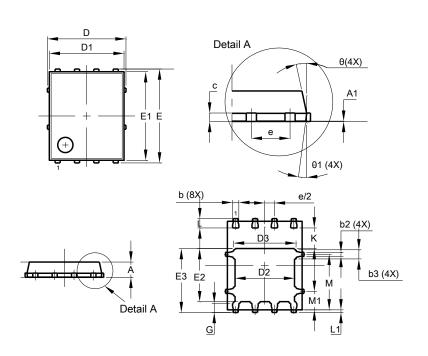
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8

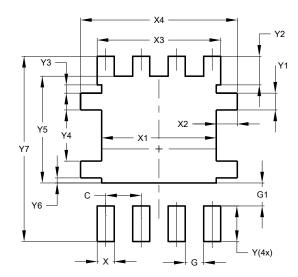


PowerDI5060-8					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00				
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D	į,	5.15 BSC	;		
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
Е	6.15 BSC				
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е	1.27 BSC				
G	0.51	0.71	0.61		
K	0.51	-	-		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
All	All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8



Dimensions	Value (in mm)			
С	1.270			
G	0.660			
G1	0.820			
X	0.610			
X1	4.100			
X2	0.755			
Х3	4.420			
X4	5.610			
Y	1.270			
Y1	0.600			
Y2	1.020			
Y3	0.295			
Y4	1.825			
Y5	3.810			
Y6	6 0.180			
Y7	6.610			



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